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LM35

SNIS159H-AUGUST 1999-REVISED DECEMBER 2017

LM35 Precision Centigrade Temperature Sensors

Technical

Documents

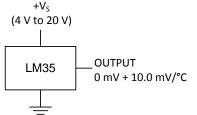
Features 1

- Calibrated Directly in Celsius (Centigrade)
- Linear + 10-mV/°C Scale Factor
- 0.5°C Ensured Accuracy (at 25°C)
- Rated for Full -55°C to 150°C Range
- Suitable for Remote Applications
- Low-Cost Due to Wafer-Level Trimming
- Operates From 4 V to 30 V
- Less Than 60-µA Current Drain
- Low Self-Heating, 0.08°C in Still Air
- Non-Linearity Only ±1/4°C Typical
- Low-Impedance Output, 0.1 Ω for 1-mA Load

2 Applications

- **Power Supplies**
- **Battery Management**
- **HVAC**
- Appliances

Basic Centigrade Temperature Sensor (2°C to 150°C)



3 Description

Tools &

Software

20

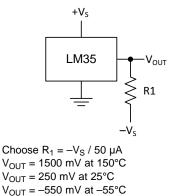
The LM35 series are precision integrated-circuit temperature devices with an output voltage linearlyproportional to the Centigrade temperature. The LM35 device has an advantage over linear temperature sensors calibrated in Kelvin, as the user is not required to subtract a large constant voltage from the output to obtain convenient Centigrade scaling. The LM35 device does not require any external calibration or trimming to provide typical accuracies of $\pm \frac{1}{2}$ °C at room temperature and $\pm \frac{3}{4}$ °C over a full -55°C to 150°C temperature range. Lower cost is assured by trimming and calibration at the wafer level. The low-output impedance, linear output, and precise inherent calibration of the LM35 device makes interfacing to readout or control circuitry especially easy. The device is used with single power supplies, or with plus and minus supplies. As the LM35 device draws only 60 µA from the supply, it has very low self-heating of less than 0.1°C in still air. The LM35 device is rated to operate over a -55°C to 150°C temperature range, while the LM35C device is rated for a -40°C to 110°C range (-10° with improved accuracy). The LM35-series devices are available packaged in hermetic TO transistor packages, while the LM35C, LM35CA, and LM35D devices are available in the plastic TO-92 transistor package. The LM35D device is available in an 8-lead surface-mount small-outline package and a plastic TO-220 package.

Device miormation ?								
PACKAGE	BODY SIZE (NOM)							
TO-CAN (3)	4.699 mm × 4.699 mm							
TO-92 (3)	4.30 mm × 4.30 mm							
SOIC (8)	4.90 mm × 3.91 mm							
TO-220 (3)	14.986 mm × 10.16 mm							
	PACKAGE TO-CAN (3) TO-92 (3) SOIC (8)							

Device Information⁽¹⁾

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Full-Range Centigrade Temperature Sensor





An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

Table of Contents

7.4

8.2

11.1

11.2 11.3

11.4

8

9

1	Feat	tures 1
2	Арр	lications1
3	Des	cription 1
4	Rev	ision History 2
5	Pin	Configuration and Functions 3
6	Spe	cifications 4
	6.1	Absolute Maximum Ratings 4
	6.2	ESD Ratings 4
	6.3	Recommended Operating Conditions 4
	6.4	Thermal Information 4
	6.5	Electrical Characteristics: LM35A, LM35CA Limits 5
	6.6	Electrical Characteristics: LM35A, LM35CA 6
	6.7	Electrical Characteristics: LM35, LM35C, LM35D Limits
	6.8	Electrical Characteristics: LM35, LM35C, LM35D 9
	6.9	Typical Characteristics 11
7	Deta	ailed Description 13
	7.1	Overview 13
	7.2	Functional Block Diagram 13

Revision History 4

2

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CI	nanges from Revision G (August 2016) to Revision H Page
•	Changed NDV Package (TO-CAN) pinout from bottom view back to top view; added textnote to pinout
CI	nanges from Revision F (January 2016) to Revision G Page
•	Equation 1, changed From: 10 mV/°F To: 10mv/°C13Power Supply Recommendations, changed From: "4-V to 5.5-V power supply" To: "4-V to 30-V power supply:
CI	nanges from Revision E (January 2015) to Revision F Page
•	Changed NDV Package (TO-CAN) pinout from Top View to Bottom View 3
CI	nanges from Revision D (October 2013) to Revision E Page
•	Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section
CI	nanges from Revision C (July 2013) to Revision D Page
•	Changed W to Q 1 Changed W to Q in Abs Max tablenote. 4

STRUMENTS

EXAS

7.3 Feature Description...... 13 Device Functional Modes..... 13

Application and Implementation 14

8.1 Application Information..... 14

10.1 Layout Guidelines 19 10.2 Layout Example 20 11 Device and Documentation Support 21

Typical Application 15 8.3 System Examples 16 Power Supply Recommendations 19

Receiving Notification of Documentation Updates 21

Trademarks 21 Electrostatic Discharge Caution 21

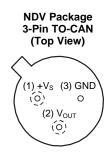
11.5 Glossary 21

12 Mechanical, Packaging, and Orderable

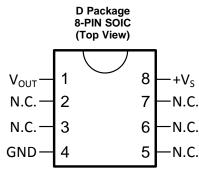
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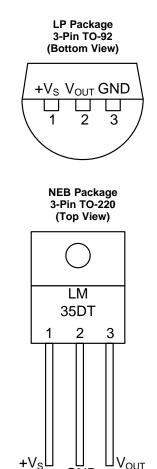
5 Pin Configuration and Functions



Case is connected to negative pin (GND) Refer the second NDV0003H page for reference



N.C. = No connection



 $+V_{S} \sqcup \sqcup U_{OUT}$

Tab is connected to the negative pin (GND).

NOTE: The LM35DT pinout is different than the discontinued LM35DP

Pin Functions

		PIN			ТҮРЕ	DESCRIPTION
NAME	TO46	TO92	TO220	SO8	ITPE	DESCRIPTION
V _{OUT}	2	2	3	1	0	Temperature Sensor Analog Output
N.C.		—		2		No Connection
N.C.		—	_	3	_	No connection
GND	3	3	2	4	GROUND	Device ground pin, connect to power supply negative terminal
	_	_	—	5		
N.C.	_	_	_	6	_	No Connection
	_	_	_	7		
+V _S	1	1	1	8	POWER	Positive power supply pin

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

			MIN	MAX	UNIT
Supply voltage		-0.2	35	V	
Output voltage			-1	6	V
Output current				10	mA
Maximum Junction Temperature, T	max			150	°C
Olama and Tanana and Anna T	TO-CAN, TO-92 Package		-60	150	**
Storage Temperature, T _{stg}	TO-220, SOIC Package –65 150	°C			

(1) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

(2) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its rated operating conditions.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Specified operating temperature: T_{MIN} to T_{MAX} Supply Voltage (+V _S)	LM35, LM35A	-55	150	
	LM35C, LM35CA	-40	110	°C
MAX	LM35D	-40 110 °C 0 100		
Supply Voltage (+V _S)		4	30	V

6.4 Thermal Information

	THERMAL METRIC ⁽¹⁾⁽²⁾	NDV	LP	D	NEB	UNIT
		3 P	INS	8 PINS	3 PINS	
R_{\thetaJA}	Junction-to-ambient thermal resistance	400	180	220	90	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	24	—	—	—	°C/vv

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

(2) For additional thermal resistance information, see *Typical Application*.



6.5 Electrical Characteristics: LM35A, LM35CA Limits

Unless otherwise noted, these specifications apply: $-55^{\circ}C \le T_{J} \le 150^{\circ}C$ for the LM35 and LM35A; $-40^{\circ}C \le T_{J} \le 110^{\circ}C$ for the LM35C and LM35CA; and $0^{\circ}C \le T_{J} \le 100^{\circ}C$ for the LM35D. $V_{S} = 5$ Vdc and $I_{LOAD} = 50 \ \mu$ A, in the circuit of Full-Range Centigrade Temperature Sensor. These specifications also apply from 2°C to T_{MAX} in the circuit of Figure 14.

	•							
		-	LM35A			LM35CA		
PARAMETER	TEST CONDITIONS	TYP	TESTED LIMIT ⁽¹⁾	DESIGN LIMIT ⁽²⁾	TYP	TESTED LIMIT ⁽¹⁾	DESIGN LIMIT ⁽²⁾	UNIT
	$T_A = 25^{\circ}C$	±0.2	±0.5		±0.2	±0.5		
Accuracy ⁽³⁾	$T_A = -10^{\circ}C$	±0.3			±0.3		±1	°C
Accuracy	$T_A = T_{MAX}$	±0.4	±1		±0.4	±1		
	$T_A = T_{MIN}$	±0.4	±1		±0.4		±1.5	
Nonlinearity ⁽⁴⁾	$T_{MIN} \le T_A \le T_{MAX},$ -40°C $\le T_J \le 125$ °C	±0.18		±0.35	±0.15		±0.3	°C
Sensor gain	$T_{MIN} \le T_A \le T_{MAX}$	10	9.9		10		9.9	mV/°C
(average slope)	–40°C ≤ T _J ≤ 125°C	10	10.1		10		10.1	mv/°C
Load regulation ⁽⁵⁾ $0 \le I_L \le 1 \text{ mA}$	$T_A = 25^{\circ}C$	±0.4	±1		±0.4	±1		mV/mA
	$T_{MIN} \le T_A \le T_{MAX},$ -40°C $\le T_J \le 125$ °C	±0.5		±3	±0.5		±3	
	$T_A = 25^{\circ}C$	±0.01	±0.05		±0.01	±0.05		
Line regulation ⁽⁵⁾	4 V ≤ V _S ≤ 30 V, –40°C ≤ T _J ≤ 125°C	±0.02		±0.1	±0.02		±0.1	mV/V
	V _S = 5 V, 25°C	56	67		56	67		
Quiescent current ⁽⁶⁾	$V_S = 5 \text{ V}, -40^{\circ}\text{C} \le T_J \le 125^{\circ}\text{C}$	105		131	91		114	
Quiescent current	V _S = 30 V, 25°C	56.2	68		56.2	68		μA
	$V_{S} = 30 \text{ V}, -40^{\circ}\text{C} \le \text{T}_{J} \le 125^{\circ}\text{C}$	105.5		133	91.5		116	
Channe of million and	4 V ≤ V _S ≤ 30 V, 25°C	0.2	1		0.2	1		
Change of quiescent current ⁽⁵⁾	4 V ≤ V _S ≤ 30 V, –40°C ≤ T _J ≤ 125°C	0.5		2	0.5		2	μA
Temperature coefficient of quiescent current	–40°C ≤ T _J ≤ 125°C	0.39		0.5	0.39		0.5	µA/°C
Minimum temperature for rate accuracy	In circuit of Figure 14, $I_L = 0$	1.5		2	1.5		2	°C
Long term stability	$T_J = T_{MAX}$, for 1000 hours	±0.08			±0.08			°C
		1						

(1) Tested Limits are ensured and 100% tested in production.

(2) Design Limits are ensured (but not 100% production tested) over the indicated temperature and supply voltage ranges. These limits are not used to calculate outgoing quality levels.

(3) Accuracy is defined as the error between the output voltage and 10 mv/°C times the case temperature of the device, at specified conditions of voltage, current, and temperature (expressed in °C).

(4) Non-linearity is defined as the deviation of the output-voltage-versus-temperature curve from the best-fit straight line, over the rated temperature range of the device.

(5) Regulation is measured at constant junction temperature, using pulse testing with a low duty cycle. Changes in output due to heating effects can be computed by multiplying the internal dissipation by the thermal resistance.

(6) Quiescent current is defined in the circuit of Figure 14.



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6.6 Electrical Characteristics: LM35A, LM35CA

Unless otherwise noted, these specifications apply: $-55^{\circ}C \le T_{J} \le 150^{\circ}C$ for the LM35 and LM35A; $-40^{\circ}C \le T_{J} \le 110^{\circ}C$ for the LM35C and LM35CA; and $0^{\circ}C \le T_{J} \le 100^{\circ}C$ for the LM35D. $V_{S} = 5$ Vdc and $I_{LOAD} = 50 \mu$ A, in the circuit of Full-Range Centigrade Temperature Sensor. These specifications also apply from 2°C to T_{MAX} in the circuit of Figure 14.

				LM35A		L	LM35CA		
PARAMETER	TEST CO	NDITIONS	MIN	ТҮР	MAX	TYP	TYP	MAX	UNIT
Accuracy ⁽¹⁾				±0.2			±0.2		
	T _A = 25°C	Tested Limit ⁽²⁾			±0.5			±0.5	
		Design Limit ⁽³⁾							-
				±0.3			±0.3		-
	$T_A = -10^{\circ}C$	Tested Limit ⁽²⁾							-
		Design Limit ⁽³⁾						±1	
Accuracy				±0.4			±0.4		°C
	$T_A = T_{MAX}$	Tested Limit ⁽²⁾			±1			±1	-
		Design Limit ⁽³⁾							-
				±0.4			±0.4		-
	$T_A = T_{MIN}$	Tested Limit ⁽²⁾			±1				-
		Design Limit ⁽³⁾						±1.5	-
Nonlinearity ⁽⁴⁾	$\begin{array}{l} T_{MIN} \leq T_A \leq T_{MAX}, \\ -40^{\circ}C \leq T_J \leq 125^{\circ}C \end{array}$			±0.18			±0.15		
		Tested Limit ⁽²⁾							°C
-		Design Limit ⁽³⁾			±0.35			±0.3	
	$T_{MIN} \le T_A \le T_{MAX}$			10			10		
		Tested Limit ⁽²⁾			9.9				- mV/°C
Sensor gain		Design Limit ⁽³⁾						9.9	
(average slope)	–40°C ≤ T _J ≤ 125°C			10			10		
		Tested Limit ⁽²⁾			10.1				
		Design Limit ⁽³⁾						10.1	-
				±0.4			±0.4		
	T _A = 25°C	Tested Limit ⁽²⁾			±1			±1	-
Load regulation ⁽⁵⁾		Design Limit ⁽³⁾							
$0 \le I_L \le 1 \text{ mA}$				±0.5			±0.5		mV/mA
	T _{MIN} ≤ T _A ≤ T _{MAX} , –40°C ≤ T _J ≤ 125°C	Tested Limit ⁽²⁾							-
	-40 C S IJ S 125 C	Design Limit ⁽³⁾			±3			±3	-
		-		±0.01			±0.01		
	T _A = 25°C	Tested Limit ⁽²⁾			±0.05			±0.05	1
		Design Limit ⁽³⁾							
Line regulation ⁽⁵⁾				±0.02			±0.02		mV/V
	4 V ≤ V _S ≤ 30 V, –40°C ≤ T _J ≤ 125°C	Tested Limit ⁽²⁾							1
	$-400 \ge 13 \ge 1200$	Design Limit ⁽³⁾			±0.1			±0.1	1

(1) Accuracy is defined as the error between the output voltage and 10 mv/°C times the case temperature of the device, at specified conditions of voltage, current, and temperature (expressed in °C).

(2) Tested Limits are ensured and 100% tested in production.

(3) Design Limits are ensured (but not 100% production tested) over the indicated temperature and supply voltage ranges. These limits are not used to calculate outgoing quality levels.

(4) Non-linearity is defined as the deviation of the output-voltage-versus-temperature curve from the best-fit straight line, over the rated temperature range of the device.

(5) Regulation is measured at constant junction temperature, using pulse testing with a low duty cycle. Changes in output due to heating effects can be computed by multiplying the internal dissipation by the thermal resistance.

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Electrical Characteristics: LM35A, LM35CA (continued)

Unless otherwise noted, these specifications apply: $-55^{\circ}C \le T_J \le 150^{\circ}C$ for the LM35 and LM35A; $-40^{\circ}C \le T_J \le 110^{\circ}C$ for the LM35C and LM35CA; and $0^{\circ}C \le T_J \le 100^{\circ}C$ for the LM35D. $V_S = 5$ Vdc and $I_{LOAD} = 50 \ \mu$ A, in the circuit of Full-Range Centigrade Temperature Sensor. These specifications also apply from 2°C to T_{MAX} in the circuit of Figure 14.

PARAMETER	TEST CONDITIONS			LM35A			M35CA		UNIT	
PARAMETER	TEST COND	MIN	TYP	MAX	TYP	TYP	MAX	UNIT		
				56			56			
	V _S = 5 V, 25°C	Tested Limit ⁽²⁾			67			67		
		Design Limit ⁽³⁾								
				105			91			
	V _S = 5 V, -40°C ≤ T _J ≤ 125°C	Tested Limit ⁽²⁾								
Quiescent	40 0 2 1 1 2 1 2 0 0	Design Limit ⁽³⁾			131			114		
current ⁽⁶⁾				56.2			56.2		μA	
	V _S = 30 V, 25°C	Tested Limit ⁽²⁾			68			68		
		Design Limit ⁽³⁾								
	V _S = 30 V, -40°C ≤ T _J ≤ 125°C			105.5			91.5			
		Tested Limit ⁽²⁾								
		Design Limit ⁽³⁾			133			116		
	4 V ≤ V _S ≤ 30 V, 25°C			0.2			0.2			
		Tested Limit ⁽²⁾			1			1		
Change of		Design Limit ⁽³⁾								
quiescent current ⁽⁵⁾	4 V ≤ V _S ≤ 30 V, –40°C ≤ T _J ≤ 125°C			0.5			0.5		μA	
		Tested Limit ⁽²⁾							l	
		Design Limit ⁽³⁾			2			2		
Temperature				0.39			0.39			
coefficient of	$-40^{\circ}C \le T_{J} \le 125^{\circ}C$	Tested Limit ⁽²⁾							µA/°C	
quiescent current		Design Limit ⁽³⁾			0.5			0.5		
Minimum				1.5			1.5			
temperature for	In circuit of Figure 14, $I_L = 0$	Tested Limit ⁽²⁾							°C	
rate accuracy	-	Design Limit ⁽³⁾			2			2		
Long term stability	$T_J = T_{MAX}$, for 1000 hours			±0.08			±0.08		°C	

(6) Quiescent current is defined in the circuit of Figure 14.

6.7 Electrical Characteristics: LM35, LM35C, LM35D Limits

Unless otherwise noted, these specifications apply: $-55^{\circ}C \le T_{J} \le 150^{\circ}C$ for the LM35 and LM35A; $-40^{\circ}C \le T_{J} \le 110^{\circ}C$ for the LM35C and LM35CA; and $0^{\circ}C \le T_{J} \le 100^{\circ}C$ for the LM35D. $V_{S} = 5$ Vdc and $I_{LOAD} = 50 \ \mu$ A, in the circuit of Full-Range Centigrade Temperature Sensor. These specifications also apply from 2°C to T_{MAX} in the circuit of Figure 14.

			LM35		L	M35C, LM35	5D			
PARAMETER	TEST CONDITIONS	ТҮР	TESTED LIMIT ⁽¹⁾	DESIGN LIMIT ⁽²⁾	ТҮР	TESTED LIMIT ⁽¹⁾	DESIGN LIMIT ⁽²⁾	UNIT		
	$T_A = 25^{\circ}C$	±0.4	±1		±0.4	±1				
Accuracy, LM35,	$T_A = -10^{\circ}C$	±0.5			±0.5		±1.5	°C		
LM35C ⁽³⁾	$T_A = T_{MAX}$	±0.8	±1.5		±0.8		±1.5	C		
	$T_A = T_{MIN}$	±0.8		±1.5	±0.8		±2			
	$T_A = 25^{\circ}C$				±0.6	±1.5				
Accuracy, LM35D ⁽³⁾	$T_A = T_{MAX}$				±0.9		±2	°C		
	$T_A = T_{MIN}$				±0.9		±2			
Nonlinearity ⁽⁴⁾	$T_{MIN} \le T_A \le T_{MAX},$ -40°C $\le T_J \le 125°$ C	±0.3		±0.5	±0.2		±0.5	°C		
Sensor gain	$T_{MIN} \le T_A \le T_{MAX},$ -40°C $\le T_J \le 125°$ C	10	9.8		10		9.8	mV/°C		
(average slope)		10	10.2		10		10.2			
Load regulation ⁽⁵⁾	$T_A = 25^{\circ}C$	±0.4	±2		±0.4	±2		mV/mA		
$0 \le I_L \le 1 \text{ mA}$	T _{MIN} ≤ T _A ≤ T _{MAX} , –40°C ≤ T _J ≤ 125°C	±0.5		±5	±0.5		±5			
	$T_A = 25^{\circ}C$	±0.01	±0.1		±0.01	±0.1				
Line regulation ⁽⁵⁾	4 V ≤ V _S ≤ 30 V, –40°C ≤ T _J ≤ 125°C	±0.02		±0.2	±0.02		±0.2	mV/V		
	V _S = 5 V, 25°C	56	80		56	80				
Quiescent current ⁽⁶⁾	$V_{\rm S} = 5 \text{ V}, -40^{\circ}\text{C} \le T_{\rm J} \le 125^{\circ}\text{C}$	105		158	91		138	μA		
	V _S = 30 V, 25°C	56.2	82		56.2	82		μΑ		
	$V_S = 30 \text{ V}, -40^{\circ}\text{C} \le T_J \le 125^{\circ}\text{C}$	105.5		161	91.5		141			
Change of quiescent	$4 \text{ V} \leq \text{V}_{\text{S}} \leq 30 \text{ V}, 25^{\circ}\text{C}$	0.2	2		0.2	2				
current ⁽⁵⁾	4 V ≤ V _S ≤ 30 V, –40°C ≤ T _J ≤ 125°C	0.5		3	0.5		3	μA		
Temperature coefficient of quiescent current	–40°C ≤ T _J ≤ 125°C	0.39		0.7	0.39		0.7	µA/°C		
Minimum temperature for rate accuracy	In circuit of Figure 14, $I_L = 0$	1.5		2	1.5		2	°C		
Long term stability	$T_J = T_{MAX}$, for 1000 hours	±0.08			±0.08			°C		

(1) Tested Limits are ensured and 100% tested in production.

(2) Design Limits are ensured (but not 100% production tested) over the indicated temperature and supply voltage ranges. These limits are not used to calculate outgoing quality levels.

(3) Accuracy is defined as the error between the output voltage and 10 mv/°C times the case temperature of the device, at specified conditions of voltage, current, and temperature (expressed in °C).

(4) Non-linearity is defined as the deviation of the output-voltage-versus-temperature curve from the best-fit straight line, over the rated temperature range of the device.

(5) Regulation is measured at constant junction temperature, using pulse testing with a low duty cycle. Changes in output due to heating effects can be computed by multiplying the internal dissipation by the thermal resistance.

(6) Quiescent current is defined in the circuit of Figure 14.



6.8 Electrical Characteristics: LM35, LM35C, LM35D

Unless otherwise noted, these specifications apply: $-55^{\circ}C \le T_{J} \le 150^{\circ}C$ for the LM35 and LM35A; $-40^{\circ}C \le T_{J} \le 110^{\circ}C$ for the LM35C and LM35CA; and $0^{\circ}C \le T_{J} \le 100^{\circ}C$ for the LM35D. $V_{S} = 5$ Vdc and $I_{LOAD} = 50 \ \mu$ A, in the circuit of Full-Range Centigrade Temperature Sensor. These specifications also apply from 2°C to T_{MAX} in the circuit of Figure 14.

				LM35			5C, LM35	D	UNIT
PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
				±0.4			±0.4		
	$T_A = 25^{\circ}C$	Tested Limit ⁽²⁾			±1			±1	
		Design Limit ⁽³⁾							
	$T_A = -10^{\circ}C$			±0.5			±0.5		
		Tested Limit ⁽²⁾							
Accuracy, LM35,		Design Limit ⁽³⁾						±1.5	°C
LM35C ⁽¹⁾				±0.8			±0.8		C
	$T_A = T_{MAX}$	Tested Limit ⁽²⁾			±1.5				
		Design Limit ⁽³⁾						±1.5	
				±0.8			±0.8		
	$T_A = T_{MIN}$	Tested Limit ⁽²⁾							
		Design Limit ⁽³⁾			±1.5			±2	
							±0.6		
	$T_A = 25^{\circ}C$	Tested Limit ⁽²⁾						±1.5	
		Design Limit ⁽³⁾							°C
							±0.9		
Accuracy, LM35D ⁽¹⁾	$T_A = T_{MAX}$	Tested Limit ⁽²⁾							
		Design Limit ⁽³⁾						±2	
	T _A = T _{MIN}						±0.9		
		Tested Limit ⁽²⁾							
		Design Limit ⁽³⁾						±2	
				±0.3			±0.2		
Nonlinearity ⁽⁴⁾	T _{MIN} ≤ T _A ≤ T _{MAX} , –40°C ≤ T _J ≤ 125°C	Tested Limit ⁽²⁾							°C
		Design Limit ⁽³⁾			±0.5			±0.5	
				10			10		
	T _{MIN} ≤ T _A ≤ T _{MAX} , –40°C ≤ T _J ≤ 125°C	Tested Limit ⁽²⁾			9.8				
Sensor gain		Design Limit ⁽³⁾						9.8	mV/°C
(average slope)				10			10		1110/ 0
		Tested Limit ⁽²⁾			10.2				
		Design Limit ⁽³⁾						10.2	
				±0.4			±0.4		
	$T_A = 25^{\circ}C$	Tested Limit ⁽²⁾			±2			±2	
Load regulation ⁽⁵⁾		Design Limit ⁽³⁾							mV/mA
0 ≤ I _L ≤ 1 mA	T /T /T			±0.5			±0.5		niv/m/A
	T _{MIN} ≤ T _A ≤ T _{MAX} , –40°C ≤ T _J ≤ 125°C	Tested Limit ⁽²⁾							
		Design Limit ⁽³⁾			±5			±5	

 Accuracy is defined as the error between the output voltage and 10 mv/°C times the case temperature of the device, at specified conditions of voltage, current, and temperature (expressed in °C).

(2) Tested Limits are ensured and 100% tested in production.

(5) Regulation is measured at constant junction temperature, using pulse testing with a low duty cycle. Changes in output due to heating effects can be computed by multiplying the internal dissipation by the thermal resistance.

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⁽³⁾ Design Limits are ensured (but not 100% production tested) over the indicated temperature and supply voltage ranges. These limits are not used to calculate outgoing quality levels.

⁽⁴⁾ Non-linearity is defined as the deviation of the output-voltage-versus-temperature curve from the best-fit straight line, over the rated temperature range of the device.



Electrical Characteristics: LM35, LM35C, LM35D (continued)

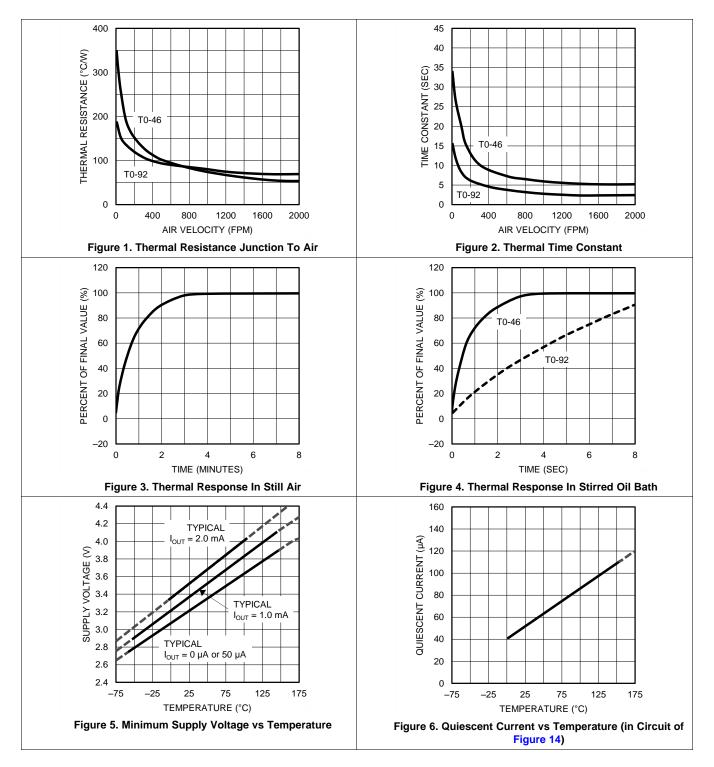
Unless otherwise noted, these specifications apply: $-55^{\circ}C \le T_{J} \le 150^{\circ}C$ for the LM35 and LM35A; $-40^{\circ}C \le T_{J} \le 110^{\circ}C$ for the LM35C and LM35CA; and $0^{\circ}C \le T_{J} \le 100^{\circ}C$ for the LM35D. $V_{S} = 5$ Vdc and $I_{LOAD} = 50 \ \mu$ A, in the circuit of Full-Range Centigrade Temperature Sensor. These specifications also apply from 2°C to T_{MAX} in the circuit of Figure 14.

	TEST CONDI	TIONS		LM35		LM3	5C, LM35	D	UNIT
PARAMETER	TEST CONDI	HUNS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
				±0.01			±0.01		
	$T_A = 25^{\circ}C$	Tested Limit ⁽²⁾			±0.1				
in a manulation (5)		Design Limit ⁽³⁾						±0.1	
Line regulation ⁽⁵⁾				±0.02			±0.02		mV/\
	4 V ≤ V _S ≤ 30 V, –40°C ≤ T _J ≤ 125°C	Tested Limit ⁽²⁾							
	40 0 2 1 3 2 1 2 0 0	Design Limit ⁽³⁾			±0.2			±0.2	
				56			56		
	V _S = 5 V, 25°C	Tested Limit ⁽²⁾			80			80	
		Design Limit ⁽³⁾							
				105			91		
	V _S = 5 V, −40°C ≤ T _J ≤ 125°C	Tested Limit ⁽²⁾							
Quiescent current ⁽⁶⁾	125 0	Design Limit ⁽³⁾			158			138	μA
	V _S = 30 V, 25°C			56.2			56.2		
		Tested Limit ⁽²⁾			82			82	
		Design Limit ⁽³⁾				·			
	V _S = 30 V, –40°C ≤ T _J ≤ 125°C			105.5		·	91.5		
		Tested Limit ⁽²⁾							
	40 0 = 1j = 120 0	Design Limit ⁽³⁾			161			141	
				0.2			0.2		
	4 V ≤ V _S ≤ 30 V, 25°C	Tested Limit ⁽²⁾				·		2	
Change of		Design Limit ⁽³⁾			2	·			
quiescent current ⁽⁵⁾				0.5		·	0.5		μA
	4 V ≤ V _S ≤ 30 V, –40°C ≤ T _J ≤ 125°C	Tested Limit ⁽²⁾							
	-40 0 3 1 3 1 2 0 0	Design Limit ⁽³⁾			3			3	
Temperature				0.39			0.39		
coefficient of $-40^{\circ}C \le T_{J} \le 125^{\circ}C$ Minimum	–40°C ≤ T _J ≤ 125°C	Tested Limit ⁽²⁾							μA/°C
		Design Limit ⁽³⁾			0.7			0.7	
				1.5			1.5		
	In circuit of Figure 14, $I_L = 0$	Tested Limit ⁽²⁾							°C
		Design Limit ⁽³⁾			2			2	-
Long term stability	$T_{\rm J} = T_{\rm MAX}$, for 1000 hours	1		±0.08			±0.08		°C

(6) Quiescent current is defined in the circuit of Figure 14.

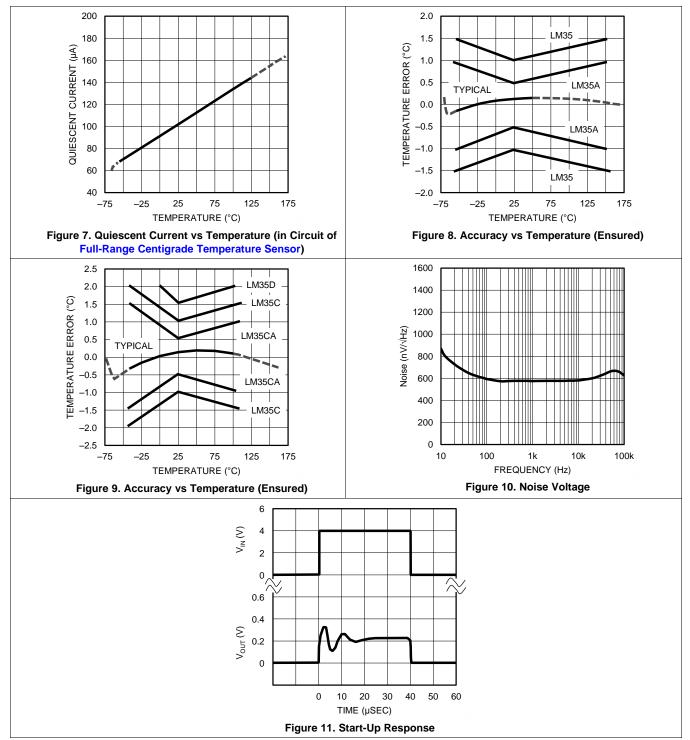


6.9 Typical Characteristics





Typical Characteristics (continued)





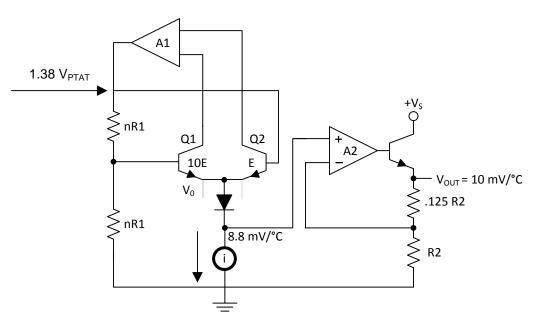
7 Detailed Description

7.1 Overview

The LM35-series devices are precision integrated-circuit temperature sensors, with an output voltage linearly proportional to the Centigrade temperature. The LM35 device has an advantage over linear temperature sensors calibrated in Kelvin, as the user is not required to subtract a large constant voltage from the output to obtain convenient Centigrade scaling. The LM35 device does not require any external calibration or trimming to provide typical accuracies of $\pm \frac{1}{4}$ °C at room temperature and $\pm \frac{3}{4}$ °C over a full -55°C to 150°C temperature range. Lower cost is assured by trimming and calibration at the wafer level. The low output impedance, linear output, and precise inherent calibration of the LM35 device makes interfacing to readout or control circuitry especially easy. The device is used with single power supplies, or with plus and minus supplies. As the LM35 device draws only 60 μ A from the supply, it has very low self-heating of less than 0.1°C in still air. The LM35 device is rated to operate over a -55°C to 150°C temperature range, while the LM35C device is rated for a -40°C to 110°C range (-10° with improved accuracy). The temperature-sensing element is comprised of a delta-V BE architecture.

The temperature-sensing element is then buffered by an amplifier and provided to the VOUT pin. The amplifier has a simple class A output stage with typical $0.5-\Omega$ output impedance as shown in the *Functional Block Diagram*. Therefore the LM35 can only source current and it's sinking capability is limited to 1 μ A.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 LM35 Transfer Function

The accuracy specifications of the LM35 are given with respect to a simple linear transfer function:

 $V_{OUT} = 10 \text{ mv/°C} \times \text{T}$

where

- V_{OUT} is the LM35 output voltage
- T is the temperature in °C

7.4 Device Functional Modes

The only functional mode of the LM35 is that it has an analog output directly proportional to temperature.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The features of the LM35 make it suitable for many general temperature sensing applications. Multiple package options expand on it's flexibility.

8.1.1 Capacitive Drive Capability

Like most micropower circuits, the LM35 device has a limited ability to drive heavy capacitive loads. Alone, the LM35 device is able to drive 50 pF without special precautions. If heavier loads are anticipated, isolating or decoupling the load with a resistor is easy (see Figure 12). The tolerance of capacitance can be improved with a series R-C damper from output to ground (see Figure 13).

When the LM35 device is applied with a 200- Ω load resistor as shown in Figure 16, Figure 17, or Figure 19, the device is relatively immune to wiring capacitance because the capacitance forms a bypass from ground to input and not on the output. However, as with any linear circuit connected to wires in a hostile environment, performance is affected adversely by intense electromagnetic sources (such as relays, radio transmitters, motors with arcing brushes, and SCR transients), because the wiring acts as a receiving antenna and the internal junctions act as rectifiers. For best results in such cases, a bypass capacitor from V_{IN} to ground and a series R-C damper, such as 75 Ω in series with 0.2 or 1 μ F from output to ground, are often useful. Examples are shown in Figure 13, Figure 24, and Figure 25.

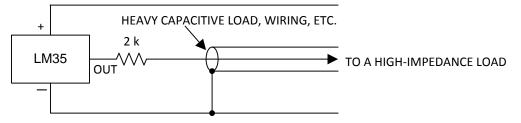


Figure 12. LM35 with Decoupling from Capacitive Load

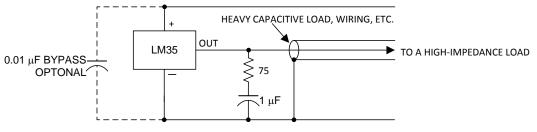


Figure 13. LM35 with R-C Damper



8.2 Typical Application

8.2.1 Basic Centigrade Temperature Sensor

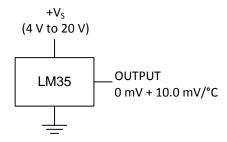


Figure 14. Basic Centigrade Temperature Sensor (2 °C to 150 °C)

8.2.1.1 Design Requirements

PARAMETER	VALUE
Accuracy at 25°C	±0.5°C
Accuracy from –55 °C to 150°C	±1°C
Temperature Slope	10 mV/°C

Table 1. Design Parameters

8.2.1.2 Detailed Design Procedure

Because the LM35 device is a simple temperature sensor that provides an analog output, design requirements related to layout are more important than electrical requirements. For a detailed description, refer to the *Layout*.

8.2.1.3 Application Curve

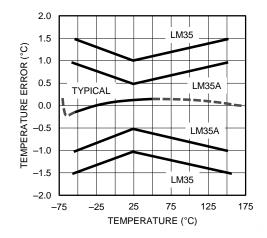
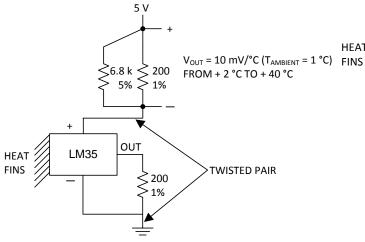


Figure 15. Accuracy vs Temperature (Ensured)

8.3 System Examples





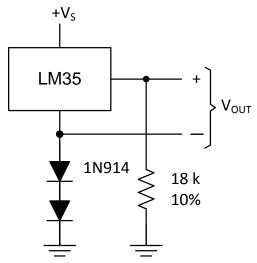


Figure 18. Temperature Sensor, Single Supply (-55° to +150°C)

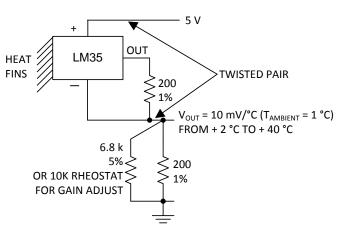


Figure 17. Two-Wire Remote Temperature Sensor (Output Referred to Ground)

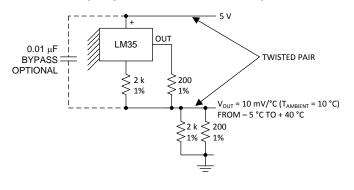
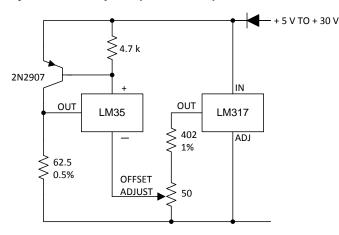
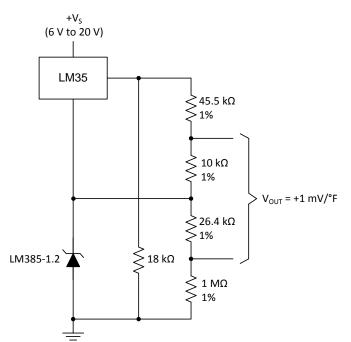


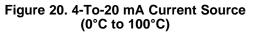
Figure 19. Two-Wire Remote Temperature Sensor (Output Referred to Ground)



System Examples (continued)







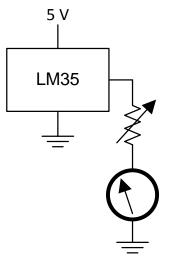




Figure 21. Fahrenheit Thermometer

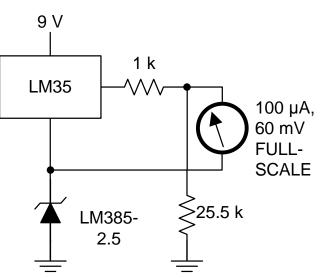


Figure 23. Fahrenheit Thermometer, Expanded Scale Thermometer (50°F to 80°F, for Example Shown)



System Examples (continued)

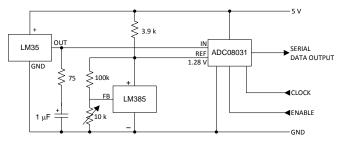
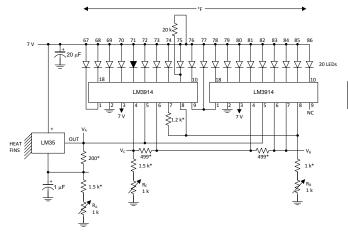


Figure 24. Temperature to Digital Converter (Serial Output) (128°C Full Scale)



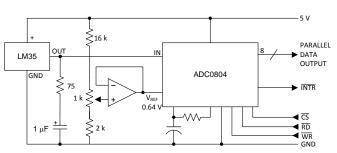
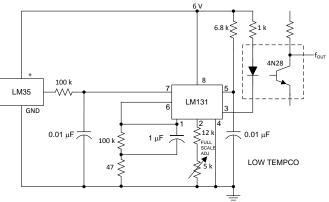


Figure 25. Temperature to Digital Converter (Parallel TRI-STATE Outputs for Standard Data Bus to μP Interface) (128°C Full Scale)



*=1% or 2% film resistor

Trim R_B for $V_B = 3.075$ V

Trim R_C for $V_C = 1.955 V$

Trim R_A for $V_A = 0.075 V + 100 mV/°C \times T_{ambient}$

Example, $V_A = 2.275 \text{ V}$ at 22°C

Figure 26. Bar-Graph Temperature Display (Dot Mode)

Figure 27. LM35 With Voltage-To-Frequency Converter and Isolated Output (2°C to 150°C; 20 to 1500 Hz)



9 Power Supply Recommendations

The LM35 device has a very wide 4-V to 30-V power supply voltage range, which makes it ideal for many applications. In noisy environments, TI recommends adding a 0.1 μ F from V+ to GND to bypass the power supply voltage. Larger capacitances maybe required and are dependent on the power-supply noise.

10 Layout

10.1 Layout Guidelines

The LM35 is easily applied in the same way as other integrated-circuit temperature sensors. Glue or cement the device to a surface and the temperature should be within about 0.01°C of the surface temperature.

The 0.01°C proximity presumes that the ambient air temperature is almost the same as the surface temperature. If the air temperature were much higher or lower than the surface temperature, the actual temperature of the LM35 die would be at an intermediate temperature between the surface temperature and the air temperature; this is especially true for the TO-92 plastic package. The copper leads in the TO-92 package are the principal thermal path to carry heat into the device, so its temperature might be closer to the air temperature than to the surface temperature.

Ensure that the wiring leaving the LM35 device is held at the same temperature as the surface of interest to minimize the temperature problem. The easiest fix is to cover up these wires with a bead of epoxy. The epoxy bead will ensure that the leads and wires are all at the same temperature as the surface, and that the temperature of the LM35 die is not affected by the air temperature.

The TO-46 metal package can also be soldered to a metal surface or pipe without damage. Of course, in that case the V- terminal of the circuit will be grounded to that metal. Alternatively, mount the LM35 inside a sealedend metal tube, and then dip into a bath or screw into a threaded hole in a tank. As with any IC, the LM35 device and accompanying wiring and circuits must be kept insulated and dry, to avoid leakage and corrosion. This is especially true if the circuit may operate at cold temperatures where condensation can occur. Printed-circuit coatings and varnishes such as a conformal coating and epoxy paints or dips are often used to insure that moisture cannot corrode the LM35 device or its connections.

These devices are sometimes soldered to a small light-weight heat fin to decrease the thermal time constant and speed up the response in slowly-moving air. On the other hand, a small thermal mass may be added to the sensor, to give the steadiest reading despite small deviations in the air temperature.

	TO, no heat sink	TO ⁽¹⁾ , small heat fin	TO-92, no heat sink	TO-92 ⁽²⁾ , small heat fin	SOIC-8, no heat sink	SOIC-8 ⁽²⁾ , small heat fin	TO-220, no heat sink
Still air	400°C/W	100°C/W	180°C/W	140°C/W	220°C/W	110°C/W	90°C/W
Moving air	100°C/W	40°C/W	90°C/W	70°C/W	105°C/W	90°C/W	26°C/W
Still oil	100°C/W	40°C/W	90°C/W	70°C/W	—	—	—
Stirred oil	50°C/W	30°C/W	45°C/W	40°C/W	_		_
(Clamped to metal, Infinite heat sink)	(24°	(24°C/W)		_	(55°C/W)		_

Table 2. Temperature Rise of LM35 Due To Self-heating (Thermal Resistance, $R_{\theta JA}$)

(1) Wakefield type 201, or 1-in disc of 0.02-in sheet brass, soldered to case, or similar.

(2) TO-92 and SOIC-8 packages glued and leads soldered to 1-in square of 1/16-in printed circuit board with 2-oz foil or similar.

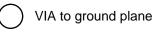
LM35

SNIS159H-AUGUST 1999-REVISED DECEMBER 2017

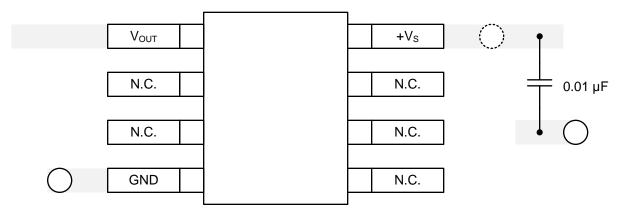
TEXAS INSTRUMENTS

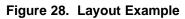
www.ti.com

10.2 Layout Example



VIA to power plane







11 Device and Documentation Support

11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on A*lert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document

11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.3 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

11.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM35AH	ACTIVE	то	NDV	3	500	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 150	(LM35AH, LM35AH)	Samples
LM35AH/NOPB	ACTIVE	то	NDV	3	500	RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 150	(LM35AH, LM35AH)	Samples
LM35CAH	ACTIVE	то	NDV	3	500	Non-RoHS & Non-Green	Call TI	Call TI	-40 to 110	(LM35CAH, LM35CAH)	Samples
LM35CAH/NOPB	ACTIVE	то	NDV	3	500	RoHS & Green	Call TI	Level-1-NA-UNLIM	-40 to 110	(LM35CAH, LM35CAH)	Samples
LM35CAZ/LFT4	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type		LM35 CAZ	Samples
LM35CAZ/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	SN	N / A for Pkg Type	-40 to 110	LM35 CAZ	Samples
LM35CH	ACTIVE	то	NDV	3	500	Non-RoHS & Non-Green	Call TI	Call TI	-40 to 110	(LM35CH, LM35CH)	Samples
LM35CH/NOPB	ACTIVE	то	NDV	3	500	RoHS & Green	Call TI	Level-1-NA-UNLIM	-40 to 110	(LM35CH, LM35CH)	Samples
LM35CZ/LFT1	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type		LM35 CZ	Samples
LM35CZ/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	SN	N / A for Pkg Type	-40 to 110	LM35 CZ	Samples
LM35DH	ACTIVE	то	NDV	3	1000	Non-RoHS & Non-Green	Call TI	Call TI	0 to 70	(LM35DH, LM35DH)	Samples
LM35DH/NOPB	ACTIVE	то	NDV	3	1000	RoHS & Green	Call TI	Level-1-NA-UNLIM	0 to 70	(LM35DH, LM35DH)	Samples
LM35DM	NRND	SOIC	D	8	95	Non-RoHS & Green	Call TI	Level-1-235C-UNLIM	0 to 100	LM35D M	
LM35DM/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 100	LM35D M	Samples
LM35DMX	NRND	SOIC	D	8	2500	Non-RoHS & Green	Call TI	Level-1-235C-UNLIM	0 to 100	LM35D M	
LM35DMX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 100	LM35D M	Samples
LM35DT	NRND	TO-220	NEB	3	45	Non-RoHS & Green	Call TI	Level-1-NA-UNLIM	0 to 100	LM35DT	

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM35DT/NOPB	ACTIVE	TO-220	NEB	3	45	RoHS & Green	(6) SN	Level-1-NA-UNLIM	0 to 100	LM35DT	Samples
LM35DZ/LFT1	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type		LM35 DZ	Samples
LM35DZ/LFT4	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type		LM35 DZ	Samples
LM35DZ/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	SN	N / A for Pkg Type	0 to 100	LM35 DZ	Samples
LM35H	ACTIVE	то	NDV	3	500	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 150	(LM35H, LM35H)	Samples
LM35H/NOPB	ACTIVE	то	NDV	3	500	RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 150	(LM35H, LM35H)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

11-Mar-2023

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Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM35DMX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM35DMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

1-Sep-2023



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM35DMX	SOIC	D	8	2500	367.0	367.0	35.0
LM35DMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

TEXAS INSTRUMENTS

www.ti.com

1-Sep-2023

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
LM35DM	D	SOIC	8	95	495	8	4064	3.05
LM35DM	D	SOIC	8	95	495	8	4064	3.05
LM35DM/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM35DT	NEB	TO-220	3	45	502	33	6985	4.06
LM35DT	NEB	TO-220	3	45	502	33	6985	4.06
LM35DT/NOPB	NEB	TO-220	3	45	502	33	6985	4.06

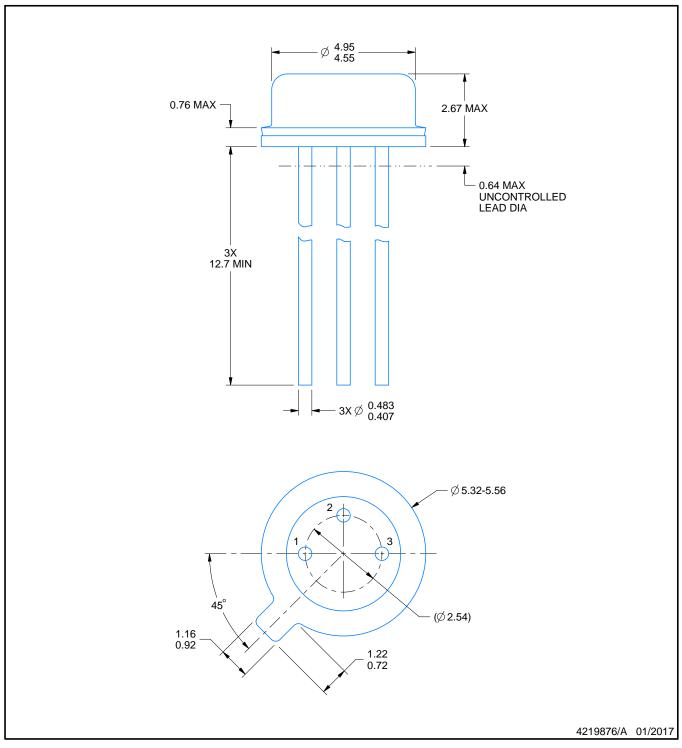
NDV0003H



PACKAGE OUTLINE

TO-CAN - 2.67 mm max height

TO-46



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration TO-46.

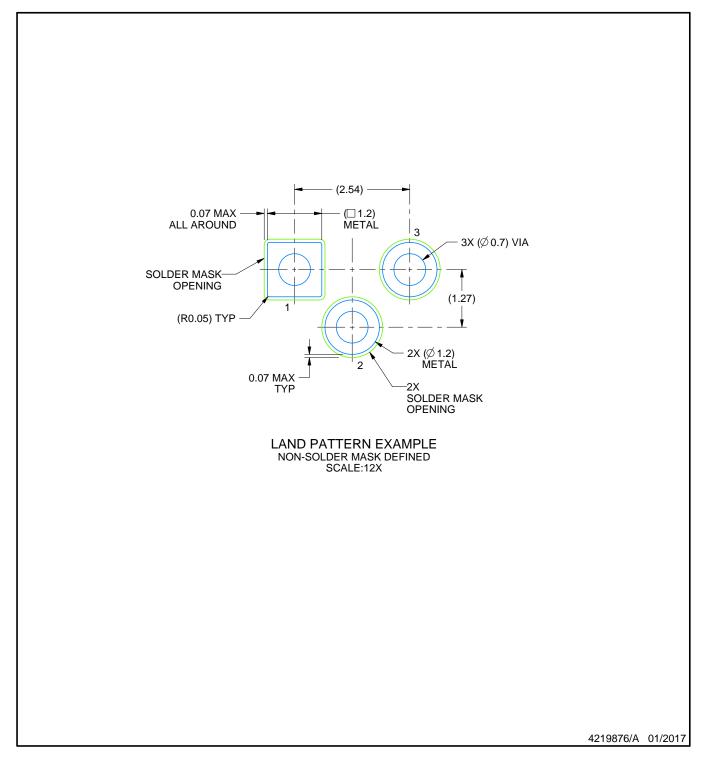


NDV0003H

EXAMPLE BOARD LAYOUT

TO-CAN - 2.67 mm max height

TO-46





D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



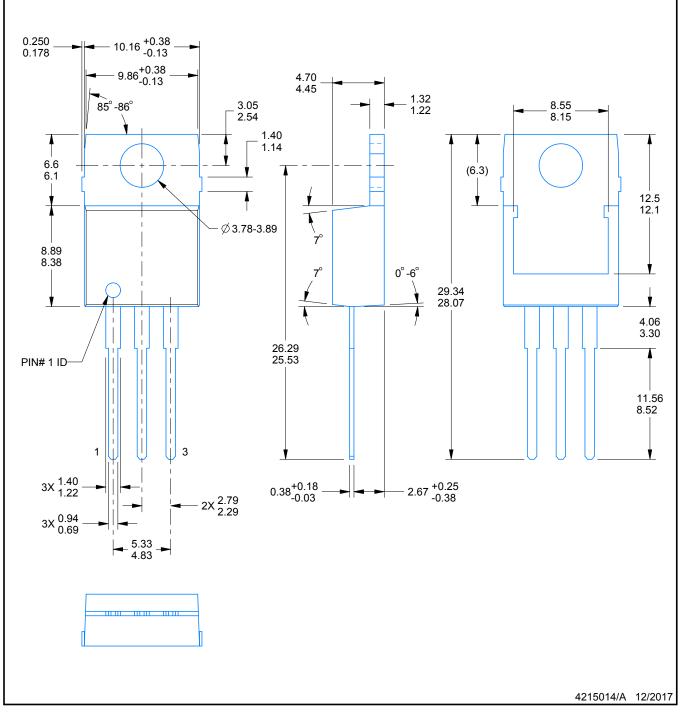
NEB0003F



PACKAGE OUTLINE

TO-220 - 19.65 mm max height

TRANSISTOR OUTLINE



NOTES:

1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

This drawing is subject to change without notice.
 Reference JEDEC registration TO-220.

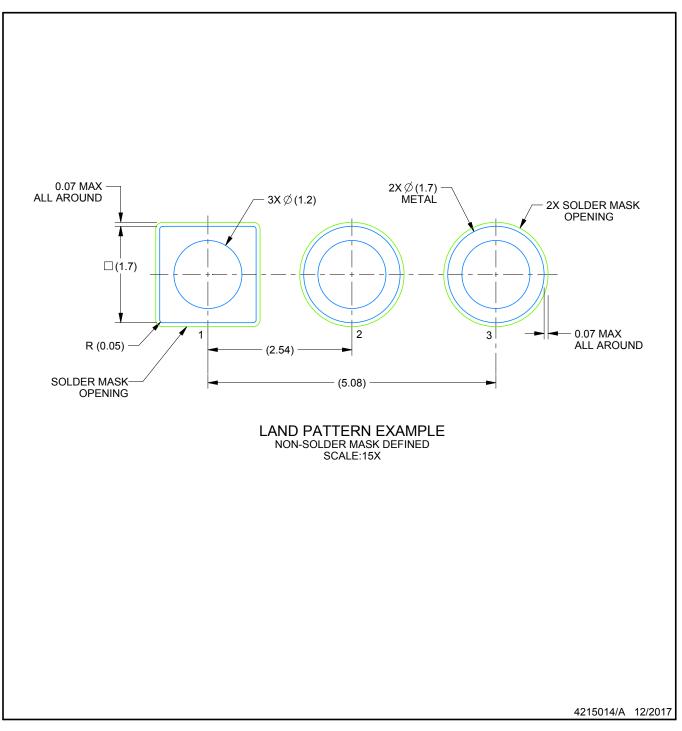


NEB0003F

EXAMPLE BOARD LAYOUT

TO-220 - 19.65 mm max height

TRANSISTOR OUTLINE





GENERIC PACKAGE VIEW

TO-92 - 5.34 mm max height TRANSISTOR OUTLINE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



LP0003A



PACKAGE OUTLINE

TO-92 - 5.34 mm max height

TO-92



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
 Reference JEDEC TO-226, variation AA.
- 5. Shipping method:

 - a. Straight lead option available in bulk pack only.b. Formed lead option available in tape and reel or ammo pack.
 - c. Specific products can be offered in limited combinations of shipping medium and lead options.
 - d. Consult product folder for more information on available options.



LP0003A

EXAMPLE BOARD LAYOUT

TO-92 - 5.34 mm max height

TO-92



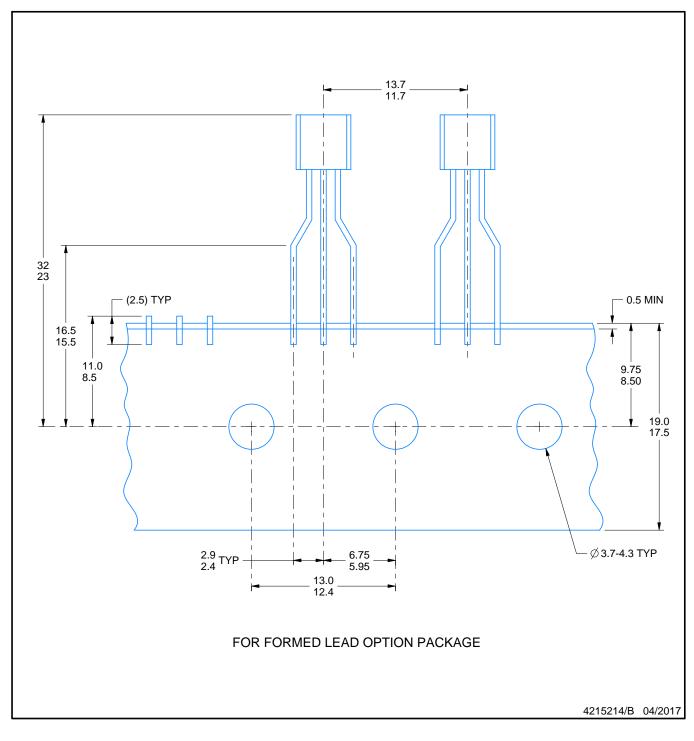


LP0003A

TAPE SPECIFICATIONS

TO-92 - 5.34 mm max height

TO-92





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